

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH273FK

Octal D-Type Flip Flop with Clear

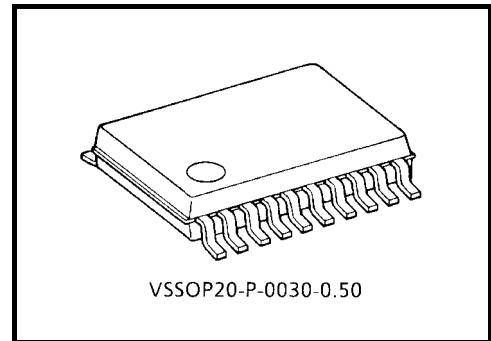
The TC7MH273FK is an advanced high speed CMOS octal D-type flip-flop fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

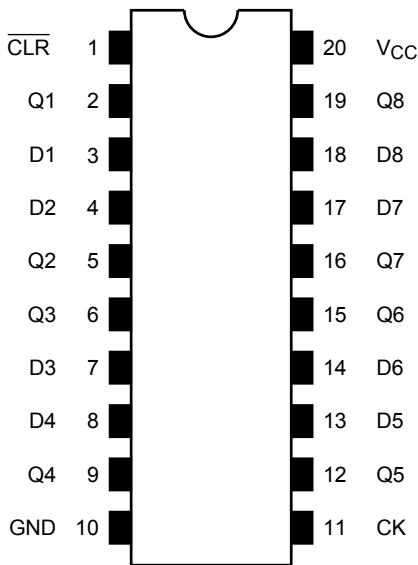


Weight: 0.03 g (typ.)

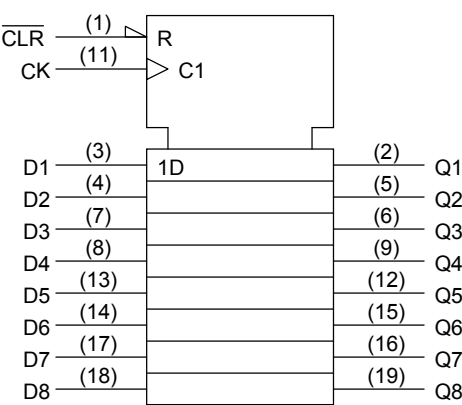
Features

- High speed: $f_{\text{max}} = 165 \text{ MHz}$ (typ.) ($V_{\text{CC}} = 5 \text{ V}$)
- Low power dissipation: $I_{\text{CC}} = 4 \mu\text{A}$ (max) ($T_a = 25^\circ\text{C}$)
- High noise immunity: $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{\text{PLH}} \approx t_{\text{PHL}}$
- Wide operating voltage range: $V_{\text{CC (opr)}} = 2 \sim 5.5 \text{ V}$
- Low noise: $V_{\text{OLP}} = 0.8 \text{ V}$ (max)
- Pin and function compatible with 74ALS273

Pin Assignment (top view)



IEC Logic Symbol

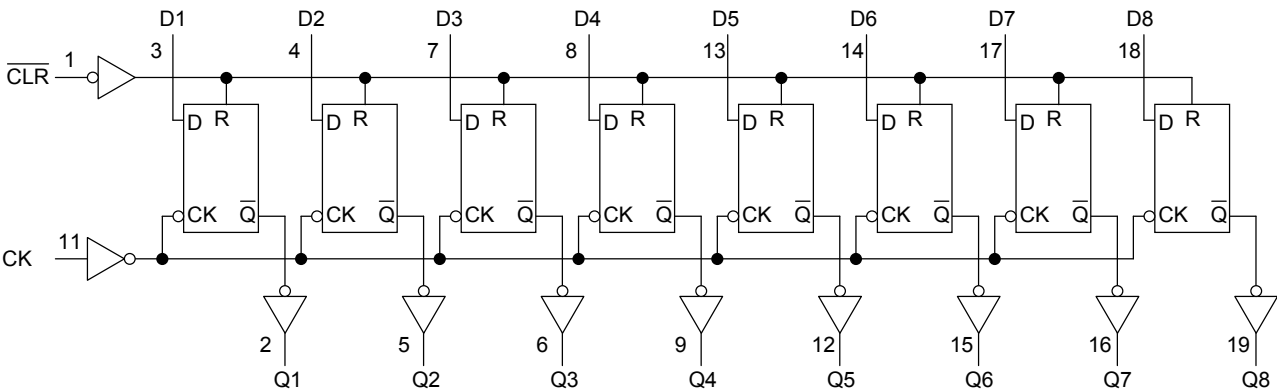


Truth Table

Inputs			Outputs	Function
CLR	D	CK	Q	
L	X	X	L	Clear
H	L		L	—
H	H		H	—
H	X		Q _n	No change

X: Don't care

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5~7.0	V
DC input voltage	V_{IN}	-0.5~7.0	V
DC output voltage	V_{OUT}	-0.5~ V_{CC} + 0.5	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC} /ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~ V_{CC}	V
Operating temperature	T_{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~100 ($V_{CC} = 3.3 \pm 0.3$ V)	ns/V
		0~20 ($V_{CC} = 5 \pm 0.5$ V)	

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C				Ta = -40~85°C		Unit		
					V _{CC} (V)	Min	Typ.	Max	Min	Max			
Input voltage	“H” level	V _{IH}	—	2.0	1.50	—	—	1.50	—	V			
				3.0~5.5	V _{CC} × 0.7	—	—	V _{CC} × 0.7	—				
	“L” level	V _{IL}	—	2.0	—	—	0.50	—	0.50				
				3.0~5.5	—	—	V _{CC} × 0.3	—	V _{CC} × 0.3				
Output voltage	“H” level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	—	V		
					3.0	2.9	3.0	—	2.9	—			
					4.5	4.4	4.5	—	4.4	—			
				I _{OH} = -4 mA	3.0	2.58	—	—	2.48	—			
					I _{OH} = -8 mA	4.5	3.94	—	—	3.80		—	
						“L” level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0		—	0
	3.0	—	0	0.1	—					0.1			
	4.5	—	0	0.1	—					0.1			
	I _{OL} = 4 mA	3.0	—	—	0.36				—	0.44			
		I _{OL} = 8 mA	4.5	—	—				0.36	—		0.44	
			Input leakage current		I _{IN}				V _{IN} = 5.5 V or GND			0~5.5	—
	Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	4.0	—		40.0	μA

Timing Requirements (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40~85°C		Unit
			V _{CC} (V)	Typ.	Limit	Limit	
Minimum pulse width (CK)	t_w (L) t_w (H)	—	3.3 ± 0.3	—	5.5	6.5	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum pulse width ($\overline{\text{CLR}}$)	t_w (L)	—	3.3 ± 0.3	—	5.0	6.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum set-up time	t_s	—	3.3 ± 0.3	—	5.5	6.5	ns
			5.0 ± 0.5	—	4.5	4.5	
Minimum hold time	t_h	—	3.3 ± 0.3	—	1.0	1.0	ns
			5.0 ± 0.5	—	1.0	1.0	
Minimum removal time ($\overline{\text{CLR}}$)	t_{rem}	—	3.3 ± 0.3	—	2.5	2.5	ns
			5.0 ± 0.5	—	2.0	2.0	

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (CK-Q)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.7	13.6	1.0	16.0	ns
				50	—	11.2	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.8	9.0	1.0	10.5	
				50	—	7.3	11.0	1.0	12.5	
Propagation delay time ($\overline{\text{CLR}}$ -Q)	t_{pHL}	—	3.3 ± 0.3	15	—	8.9	13.6	1.0	16.0	ns
				50	—	11.4	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.2	8.5	1.0	10.0	
				50	—	6.7	10.5	1.0	12.0	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	75	120	—	65	—	MHz
				50	50	75	—	45	—	
			5.0 ± 0.5	15	120	165	—	100	—	
				50	80	110	—	70	—	
Output to output skew	t_{osLH} t_{osHL}	(Note1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C _{IN}	—	—	—	—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note2)	—	—	—	31	—	—	—	pF

Note1: This parameter is guaranteed by design.

$$t_{\text{osLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, t_{\text{osHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|$$

Note2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{\text{CC (opr)}} = C_{\text{PD}} \cdot V_{\text{CC}} \cdot f_{\text{IN}} + I_{\text{CC}}/8 \text{ (per F/F)}$$

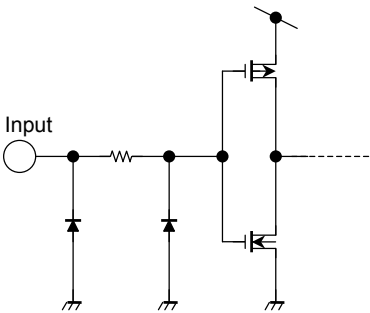
And the total C_{PD} when n pcs of flip-flop operate can be gained by the following equation:

$$C_{\text{PD (total)}} = 22 + 9 \cdot n$$

Noise Characteristics (Input: $t_r = t_f = 3\text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V _{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage V _{IH}	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage V _{IL}	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V

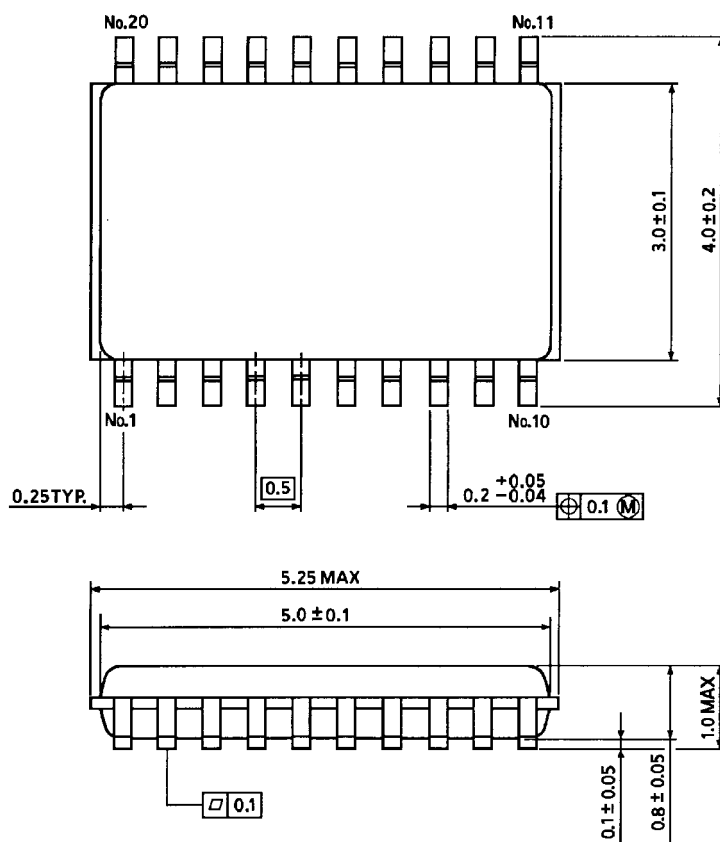
Input Equivalent Circuit



Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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